			11910	
	Application No.	Applicant(s)	N.	
Notice of Allowability	10/814,710	LINGA ET AL.		
	Examiner	Art Unit		
	Tu-Tu Ho	2818		
The MAILING DATE of this communication appe All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in this a or other appropriate communication GHTS. This application is subject	application. If not included on will be mailed in due of	i ourse. THIS	
1. This communication is responsive to Amendment filed 11/1	<u>14/2005</u> .			
2. X The allowed claim(s) is/are <u>1-63</u> .				
3. Acknowledgment is made of a claim for foreign priority un a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have 4. Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE" of noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 4. A SUBSTITUTE OATH OR DECLARATION must be submit INFORMAL PATENT APPLICATION (PTO-152) which give can be including changes required by the Notice of Draftsperson of the Paper No./Mail Date (b) including changes required by the attached Examiner's Paper No./Mail Date Identifying indicia such as the application number (see 37 CFR 1. each sheet. Replacement sheet(s) should be labeled as such in the paper No./Mail Date	been received. been received in Application No. cuments have been received in this of this communication to file a repl ENT of this application. itted. Note the attached EXAMINE as reason(s) why the oath or decla t be submitted. on's Patent Drawing Review (PTC a Amendment / Comment or in the 84(c)) should be written on the draw he header according to 37 CFR 1.12	s national stage applications in the front (not the total).	nirements OTICE OF	
 DEPOSIT OF and/or INFORMATION about the depose attached Examiner's comment regarding REQUIREMENT F Attachment(s) □ Notice of References Cited (PTO-892) 	FOR THE DEPOSIT OF BIOLOGI			
2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948)	6. ☐ Interview Summar		.02)	
	Paper No./Mail D	Paper No./Mail Date .		
 Information Disclosure Statements (PTO-1449 or PTO/SB/08 Paper No./Mail Date 03/31/2004 	8), 7. Examiner's Amend	dment/Comment		
4. Examiner's Comment Regarding Requirement for Deposit	8. 🛛 Examiner's Staten	nent of Reasons for Allow	ance	
of Biological Material	9.	770		
		To Tollie Mar Co	2005	
		Tu-Tu Ho Nov. 21,	2005	

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DETAILED ACTION

1. Applicant's Amendment filed 11/14/2005 has been reviewed and placed of record in the file.

Information Disclosure Statement

2. The information disclosure statement filed 03/31/2004 fails to comply with 37 CFR 1.98(a)(2), which requires a legible copy of each cited foreign patent document; each non-patent literature publication or that portion which caused it to be listed; and all other information or that portion which caused it to be listed. It has been placed in the application file, but the information referred to therein has not been considered.

Allowable Subject Matter

3. Claims 1-63 are allowable over the prior art of record.

The allowable subject matter was indicated in the Ex Parte Quayle Office Action mailed 10/14/2005 and recited here:

The prior art of record fails to teach or render obvious a light emitting diode and a method of fabricating thereof with all exclusive limitations as recited in claims 1 and 43, comprising a diamond substrate, a first aluminum gallium nitride (AlGaN) layer above the diamond substrate, a multiple quantum well (MQW) structure including GaN, Al, and In materials on the first AlGaN layer, a second AlGaN layer on the MQW structure, a contact structure on the second AlGaN layer, an ohmic contact to the diamond substrate, and an ohmic

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contact to the contact structure, wherein the limitation "ohmic contact to" in the limitation "an ohmic contact to the diamond substrate" has been fully considered.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tu-Tu Ho whose telephone number is (571) 272-1778. The examiner can normally be reached on 6:30 am - 5:00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, DAVID NELMS can be reached on (571) 272-1787. The fax phone number for the organization where this application or proceeding is assigned is (571) 273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Tu-Tu Ho

November 21, 2005